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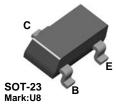
September 2012



# BSR14 NPN General Purpose Amplifier

## Features

- This device is for use as a medium power amplifier and switch requiring collector currents up to 500 mA.
- Sourced from Process 19.
- See BCW65C for characteristics.



# **Absolute Maximum Ratings**<sup>\*</sup> $T_a = 25^{\circ}C$ unless otherwise noted

| Symbol                           | Parameter  | Value       | Units |  |
|----------------------------------|--|-------------|-------|--|
| V <sub>CEO</sub>                 | Collector-Emitter Voltage                        | 40          | V     |  |
| V <sub>CBO</sub>                 | Collector-Base Voltage                           | 75          | V     |  |
| V <sub>EBO</sub>                 | Emitter-Base Voltage                             | 6.0         | V     |  |
| Ι <sub>C</sub>                   | Collector Current - Continuous                   | 800         | mA    |  |
| T <sub>J,</sub> T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |  |

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. **NOTES:** 

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### **Thermal Characteristics** $T_a = 25^{\circ}C$ unless otherwise noted

| Symbol                | Parameter                               | Max.   | Units |  |
|-----------------------|---|--------|-------|--|
|                       |   | *BSR14 |       |  |
| PD                    | Total Device Dissipation                | 350    | mW    |  |
|                       | Derate above 25°C                       | 2.8    | mW/°C |  |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance, Junction to Ambient | 357    | °C/W  |  |

\* Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

| Symbol               | Parameter                            | Test Condition  | Min.                              | Max.       | Units  |
|----------------------|--------------------------------------|---|-----------------------------------|------------|--------|
| OFF CHARAC           | TERISTICS                            |   |                                   |            |        |
| V <sub>(BR)CEO</sub> | Collector-Emitter Breakdown Voltage  | $I_{\rm C} = 10 \mu A, I_{\rm B} = 0$   | 40                                |            | V      |
| V <sub>(BR)CBO</sub> | Collector-Base Breakdown Voltage     | $I_{C} = 10\mu A, I_{E} = 0$  | 75                                |            | V      |
| V <sub>(BR)EBO</sub> | Emitter-Base Breakdown Voltage       | $I_{E} = 10 \mu A, I_{C} = 0$   | 6.0                               |            | V      |
| I <sub>CBO</sub>     | Collector-Cutoff Current             | V <sub>CB</sub> = 60V,  |                                   | 10         | nA     |
|                      |                                      | $V_{CB} = 60V, T_a = 150^{\circ}C$  |                                   | 10         | μΑ     |
| I <sub>CEX</sub>     | Collector-Cutoff Current             | $V_{CE} = 60V, V_{EB} = 3.0V$   |                                   | 10         | nA     |
| I <sub>BEX</sub>     | Reverse Base Current                 | $V_{CE} = 60V, V_{EB} = 3.0V$   |                                   | 20         | nA     |
| I <sub>EBO</sub>     | Emitter-Cutoff Current               | $V_{EB} = 3.0V, I_{C} = 0$  |                                   | 15         | nA     |
| ON CHARAC            | TERISTICS                            | •   |                                   |            |        |
| h <sub>FE</sub>      | DC Current Gain                      | $      I_{C} = 0.1 \text{mA}, V_{CE} = 10 \text{V} \\       I_{C} = 1.0 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 10 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 150 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 150 \text{mA}, V_{CE} = 1.0 \text{V} \\        I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 10 \text{V} \\        I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V} \\        I_{C} = 10 V$ | 35<br>50<br>75<br>100<br>50<br>40 | 300        |        |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | $I_{C} = 150$ mA, $I_{B} = 15$ mA<br>$I_{C} = 500$ mA, $I_{B} = 50$ mA  |                                   | 0.3<br>1.0 | V<br>V |
| V <sub>BE(sat)</sub> | Base-Emitter Saturation Voltage      | $I_{C} = 150$ mA, $I_{B} = 15$ mA<br>$I_{C} = 500$ mA, $I_{B} = 50$ mA  | 0.6                               | 1.2<br>2.0 | V<br>V |
| SMALL SIGN           | AL CHARACTERISTICS                   |   |                                   |            |        |
| f <sub>T</sub>       | Current Gain - Bandwidth Product     | $I_{C} = 20$ mA, $V_{CE} = 20$ V,<br>f = 100mHz   | 300                               |            | MHz    |
| C <sub>CB</sub>      | Collector-Base Capacitance           | $V_{CB} = 10V, I_E = 0,$<br>f = 1.0MHz  |                                   | 8.0        | pF     |
| h <sub>ie</sub>      | Input Impedance                      | $V_{CE} = 10V, I_{C} = 1.0mA,$<br>f = 1.0kHz  | 2.0                               | 8.0        | kΩ     |
| h <sub>fe</sub>      | Small-Signal Current Gain            | $V_{CE} = 10V, I_{C} = 1.0mA,$<br>f = 1.0kHz  | 50                                | 300        |        |
| h <sub>oe</sub>      | Output Admittance                    | $V_{CE} = 10V, I_{C} = 1.0mA,$<br>f = 1.0kHz  | 5                                 | 35         | μS     |
| SWITCHING            | CHARACTERISTICS                      |   |                                   | 1          |        |
| t <sub>d</sub>       | Delay Time                           | $V_{CC}$ = 30V, $V_{BE(OFF)}$ =   |                                   | 10         | ns     |
| t <sub>r</sub>       | Rise Time                            | $0.5V, I_{C} = 150mA, I_{B1} = 15mA$  |                                   | 25         | ns     |
| t <sub>s</sub>       | Storage Time                         | $V_{CC} = 30V, I_{C} = 150mA,$  |                                   | 225        | ns     |
| t <sub>f</sub>       | Fall Time                            | I <sub>B1</sub> = I <sub>B2</sub> = 15mA  |                                   | 60         | ns     |

# Spice Model

NPN (Is=14.34f Xti=3 Eg=1.11 Vaf=74.03 Bf=255.9 Ne=1.307 Ise=14.34f Ikf=.2847 Xtb=1.5 Br=6.092 Nc=2 Isc=0 Ikr=0 Rc=1 Cjc=7.306p Mjc=.3416 Vjc=.75 Fc=.5 Cje=22.01p Mje=.377 Vje=.75 Tr=46.91n Tf=411.1p Itf=.6 Vtf=1.7 Xtf=3 Rb=10)

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